

Monolithic 2-Channel FET Switch Driver

FEATURES

- Complementary Outputs
- 150 ns Propagation Time
- 30 V Output Swing
- Current Source Coupling
- TTL Compatible

BENEFITS

- Versatile
- Minimizes Switching Time
- Easily Interfaced

APPLICATIONS

- Interfaces Low Level Signal to FET Switches
- TTL to CMOS
- TTL to PROM Logic Levels
- Double-throw Switch Control

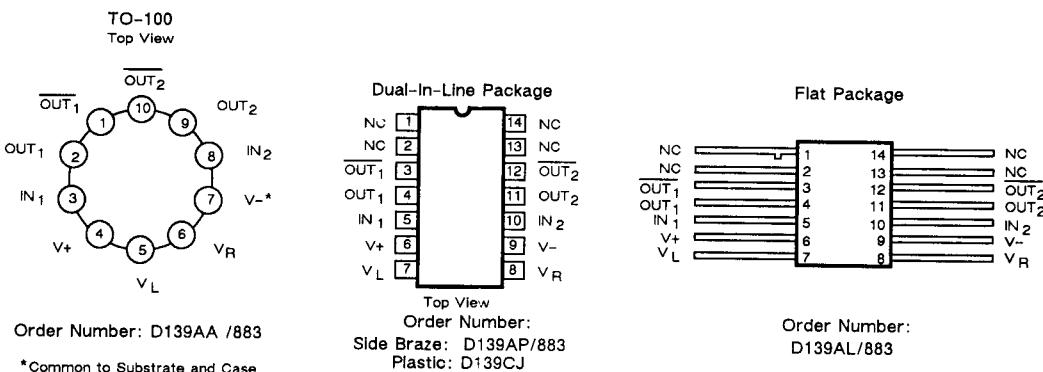
DESCRIPTION

The D139 is a dual low level to high level voltage translator with complementary outputs. Uses include bipolar to MOS logic interface and bipolar logic to FET analog switch control. The following characteristics of the input circuit provide an ideal interface to the common logic forms TTL, CMOS, and DTL: light loading (-1/3 TTL load) to "0" inputs, a 1.2 V trip point, and high input impedance with high breakdown to "1" inputs. The output can drive up to 30 V peak-to-peak into pure capacitive loads or moderate resistive loads. Current source coupling between the input and output and split

power supplies allow wide flexibility in the actual output voltage levels. Complementary outputs permit maximum application versatility, allowing functions such as a double-throw analog switch control. A positive logic "1" at the input provides a "1" at OUT and a "0" at OUT.

The D139 is offered in 10-pin metal can, plus 14-pin PDIP, side braze and flat pack packages. Performance grades include military, A suffix (-55 to 125°C) and commercial, C suffix (0 to 70°C) temperature range.

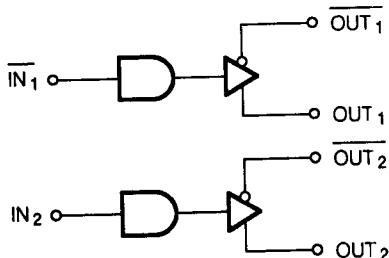
PIN CONFIGURATION



Order Number: D139AA /883

*Common to Substrate and Case

FUNCTIONAL BLOCK DIAGRAM



LOGIC	OUT	\overline{OUT}
0	V-	V+
1	V+	V-

Logic "0" \leq 0.8 VLogic "1" \geq 2.0 V

ABSOLUTE MAXIMUM RATINGS

$V_+ \text{ to } V_-$	36 V	Operating Temperature (A Suffix)	-55 to 125°C
$V_+ \text{ to } V_R$	36 V	(C Suffix)	0 to 70°C
$V_+ \text{ to } V_O$	36 V	Storage Temperature (A Suffix)	-65 to 150°C
$V_L \text{ to } V_R$	8 V	(C Suffix)	-65 to 125°C
$V_{IN} \text{ to } V_R$	8 V	Power Dissipation* (L Package)**	900 mW
$V_R \text{ to } V_-$	36 V	(P Package)***	825 mW
$V_L \text{ to } V_-$	36 V	(A Package)****	450 mW
$V_O \text{ to } V_-$	8 V	Thermal Resistance (θ_{JA} , J Package)	0.16°C/mW
$V_L \text{ to } V_{IN}$	8 V	* All leads soldered or welded to PC board.	
CURRENT, (Any Terminal) DC	12 mA	** Derate 10 mW/°C above 75°C.	
Peak Current (Any Terminal) (200 μ s pulse width, 100 pps)	100 mA	*** Derate 11 mW/°C above 75°C.	
		**** Derate 6 mW/°C above 25°C.	

ELECTRICAL CHARACTERISTICS ^a

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 10 \text{ V}$, $V_L = 5 \text{ V}$ $V_- = -20 \text{ V}$, $V_R = 0 \text{ V}$			LIMITS						UNIT	
		1=25°C 2=125, 70°C 3=-55, 0°C		A SUFFIX -55 to 125°C		C SUFFIX 0 to 70°C						
		TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b	MAX ^b					
OUTPUT												
Output Voltage HIGH $V_+ \text{ to } V_O$	$V_{OH}, V_{\overline{OH}}$	$V_{IH} = 2 \text{ V}$ for V_{OH}	$I_{OUT} = -10 \mu\text{A}$	1 2 3	0.6		0.9 0.7 1.1		0.9 0.7 1.1		V	
			$I_{OUT} = -2 \text{ mA}$	1, 2, 3	0.82		1.5		1.5			
Output Voltage LOW $V_O \text{ to } V_-$	$V_{OL}, V_{\overline{OL}}$	$V_{IL} = 0.8$ for V_{OL}	$I_{OUT} = 10 \mu\text{A}$	1 2 3	0.52		1.1 0.9 1.3		1.1 0.9 1.3			
			$I_{OUT} = 2 \text{ mA}$	1, 2, 3			1.5		1.5			
INPUT												
Input Current Voltage HIGH	I_{INH}	$V_{IN} = 5 \text{ V}$		1 2	0.003		10 20		10 20		μA	
Input Current Voltage LOW	I_{INL}	$V_{IN} = 0 \text{ V}$		1, 2 3	-18 -500 -600			-500 -600				

Not Recommended for New Designs

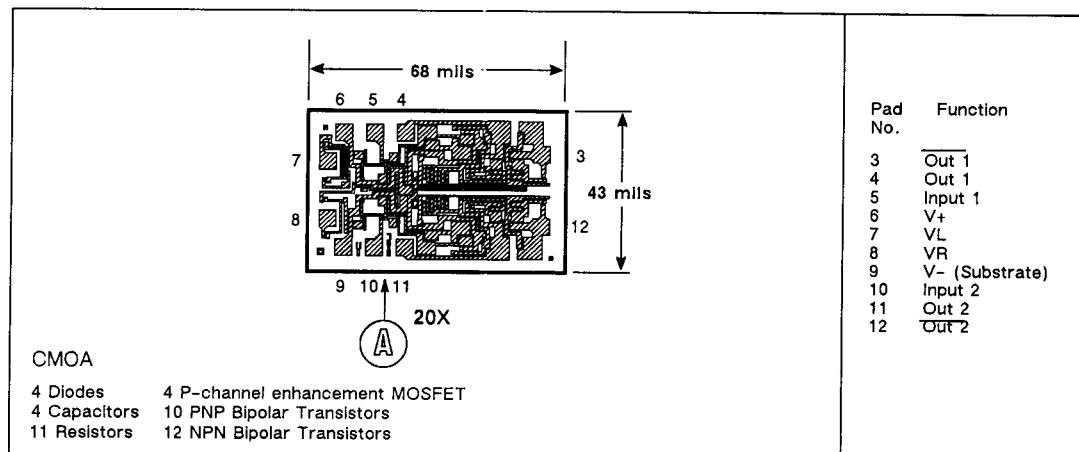
ELECTRICAL CHARACTERISTICS ^a

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: V ₊ = 10 V, V _L = 5 V V ₋ = -20 V, V _R = 0 V	LIMITS					UNIT	
			1=25°C 2=125, 70°C 3=-55, 0°C		A SUFFIX -55 to 125°C		C SUFFIX 0 to 70°C		
			TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b	MAX ^b	
DYNAMIC									
Switching Time LOW to High, Delay Plus Rise Time	t ₍₊₎	See Switching Time Test Circuit C _L = 35 pF	1	65		170		170	ns
Switching Time HIGH to Low, Delay Plus Fall Time	t ₍₋₎		1	90		200		200	
SUPPLY									
Positive Supply Current	I ₊	V _{IN} = 0 or 5 V	1	0.01		0.1		0.1	mA
Logic Supply Current	I _L		1	2.2		4		4	
Negative Supply Current	I ₋		1	-1.6	-3		-3		
Reference Supply Current Input Voltage HIGH	I _{RH}	V _{IN1} = V _{IN2} = 5 V	1	-0.66	-1.6		-1.6		
Reference Supply Current Input Voltage LOW	I _{RL}	V _{IN1} = V _{IN2} = 0 V	1	-0.63	-1.1		-1.1		

NOTES:

- a. Refer to PROCESS OPTION FLOWCHART for additional information.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Guaranteed by design, not subject to production test.
- d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- e. All dc parameters are 100% tested at 25°C. Lots are sample-tested for ac parameters and HIGH and LOW temperature limits to assure conformance with specifications.

DIE TOPOGRAPHY



SWITCHING TIME TEST CIRCUIT

